

Thursday, March 11, 2010

Opening remark (9:20-9:30)

Invited Talks 1 (9:30-12:10)

9:30 I-01 **New formation process of solar-grade Si from metallurgical-grade Si by chemical transport in near atmospheric-pressure hydrogen plasma**
K. Yasutake, H. Ohmi, and H. Kakiuchi
Osaka University, Japan, JST, CREST, Japan

10:05 I-02 **PLASMAS IN LIQUIDS AND THEIR APPLICATIONS**
B. Graham
Queen's University Belfast, UK

Coffee Break (10:40-11:00)

11:00 I-03 **Future prospects in plasma etching**
O. Joubert¹, E. Pargon¹, G. Cunge¹, T. Chevolleau¹, M. Darnon¹, L. Vallier¹, T. David²,
S. Barnola², and T. Lill³
¹LTM (CNRS-UJF-INPG), France, ²CEA-LETI, France, ³Applied Materials Inc., USA

11:35 I-04 **Plasma nanoscience: synergies and opportunities**
K. Ostrikov
CSIRO Materials Science and Engineering, Australia, The University of Sydney, Australia

Lunch (12:10-13:20)

Invited Talks 2 (13:20-15:05)

13:20 I-05 **Plasma Biology: What happens when cells meet plasma molecules?**
M.G. Kong
Loughborough University, UK

13:55 I-06 **Nanobiodevice from Single Biomolecule and Cell Analysis to Biomedical Applications**
Y. Baba
Nagoya University, Japan, National Institute of Advanced Industrial Science and Technology (AIST), Japan

14:30 I-07 **PLASMA MEDICINE**
A. Fridman
Drexel University, USA

Coffee Break (15:05-15:25)

Contributed Talks 1 (15:25-17:05)

- 15:25 O-01 **Bacterial inactivation using atmospheric pressure capillary tube based micro-plasma system with hollow inner electrode**
C.-C. Weng¹, T.-Y. Lin¹, H.-H. Chen¹, J.-D. Liao¹, C.-C. Ho², and Y.-T. Ho²
¹National Cheng Kung University, Taiwan, ²Taiwan Plasma Corp., Taiwan
- 15:45 O-02 **Plasma needle treatments of the human peripheral blood-derived multipotent mesenchymal stem cells (hPB-MS-C)**
S. Lazović¹, N. Puač¹, M. Miletic², D. Maletić¹, G. Malović¹, D. Bugarski³, S. Mojsilović³, P. Milenković², and Z. Lj. Petrović¹
¹Institute of Physics, Serbia, ²Faculty of Stomatology, Serbia, ³Institute for the Medical Research, Serbia
- 16:05 O-03 **Computer simulation of 3C-SiC powder production at initial stage of nucleation**
A. Bondareva, and G. Zmievskaya
M.V. Keldysh institute of applied mathematics of Russian Academy of Sciences, Russia
- 16:25 O-04 **Raman and AFM studies of fabricated Graphitic Carbon Nanostructures on n-Si <111> With Extremely Non-Equilibrium Plasma conditions**
Y. Malhotra, S. Roy, and M.P. Srivastava
University of Delhi, India
- 16:45 O-X **Study of hafnium oxide nano-scale film deposited using Dense Plasma Focus as a gate dielectric for a MOS device**
A. Srivastava¹, and Y. Malhotra²
¹Indian Institute for Information Technology, India, ²University of Delhi, India

Poster Session (17:10-18:40)

- P-01 **In-situ growth of a single nano needle on a metal whisker induced by periodically scanning electron beam and its field emission property**
B. Liang, C. Chen, A. Ogino, and M. Nagatsu
Shizuoka University, Japan
- P-02 **Non-isothermal Growth of Carbon Nanotubes**
F.-L. Lu, W.-Y. Chen, and J.-M. Ting
National Cheng Kung University, Taiwan

- P-03 **Synthesis and Fabrication of Functional Nanomaterials**
J. Hahm
Penn State University, USA
- P-04 **In-situ observations of growth processes of carbon nanowalls using spectroscopic ellipsometry**
K. Yasuda¹, S. Kondo¹, K. Yamakawa², H. Kondo¹, M. Hiramatsu³, M. Sekine¹, and M. Hori¹
¹Nagoya University, Japan, ²Katagiri Engineering Co., Ltd., Japan, ³Meijo University, Japan
- P-05 **Identification of carbon nanostructures obtained by synthesis of powder residues from discarded tires**
R. Mis-Fernández¹, C.R. Rios-Soberanis¹, J. Arenas-Alatorre², and J.A. Azamar-Barrios³
¹Centro de Investigación Científica de Yucatán, Unidad de Materiales, México, ²Instituto de Física de la UNAM, Departamento de Materia Condensada, México, ³Centro de Investigación y de Estudios Avanzados (CINVESTAV) del IPN-Unidad Mérida, México
- P-06 **Investigation of influence of Single Carbon Nano Wall structure on Field Effect Transistor electrical parameters and characteristics**
A. Malinowski^{1,2,3}, M. Hori¹, M. Sekine¹, H. Kondo¹, L. Lukasiak², A. Jakubowski², and D. Tomaszewski³
¹Nagoya University, Japan, ²Warsaw University of Technology, Poland, ³Institute of Electron Technology, Poland
- P-07 **Dense Plasma Focus assisted formation of Carbon Nanoloops on Quartz substrate**
S. Roy, and M.P. Srivastava
University of Delhi, India
- P-08 **Synchrotron X-ray diffraction analyses of carbon nanowalls synthesized by radical-injection plasma-enhanced chemical vapor deposition system**
H. Kondo¹, W. Takeuchi¹, S. Kondo¹, K. Yamakawa², M. Hiramatsu³, M. Sekine¹, and M. Hori¹
¹Nagoya University, Japan, ²Katagiri Engineering Co., Ltd., Japan, ³Meijo University, Japan
- P-09 **Diamond Deposition on Thick Substrates by Cooled Acetylene/Oxygen Combustion Flame**
Y. Ando
Ashikaga Institute of Technology, Japan
- P-10 **Increase of Young's modulus of diamond-like carbon by using Adamantane as Precursor Material in Plasma-Enhanced CVD**
S. Moroto, H. Kousaka, and N. Umehara
Nagoya University, Japan

- P-11 **Hardness increase of amorphous carbon film coated by pulsed-plasma ablation of PTFE**
S. Kawara¹, H. Koizumi², H. Kousaka¹, K. Yamada³, and N. Umehara¹
¹Nagoya University, Japan, ²Japan Aerospace Exploration Agency, Japan, ³Asahi Glass Co. Ltd., Japan
- P-12 **The rotational temperature of the CH radical differentiates hydrogenated amorphous carbon etching from deposition**
T.A.R. Hansen, P.G.J. Colsters, M.C.M. van de Sanden, and R. Engeln
Eindhoven University of Technology, The Netherlands
- P-13 **Light Extraction Enhancement of GaN-based Light Emitting Diodes using Nano-patterned Sapphire Substrates**
S.-M. Kim¹, H.-S. Oh¹, J.-H. Baek¹, S.-Y. Park², and W.-H. Huh²
¹Korea Photonics Technology Institute (KOPTI), Korea, ²Extol Inc., Nagoya University, Korea
- P-14 **Simulation and Experimental Verification of Inductively-Coupled Fluorocarbon Plasmas**
F. Itazu¹, K. Nakamura¹, and M. Tanaka²
¹Chubu University, Japan, ²PEGASUS Software Inc., Japan
- P-15 **Applying Reactive Ion Etching for the Fabrication of PhoXonic Crystals**
D. Dudek¹, V. Reboud¹, N. Kehagias¹, J. Cuffe¹, and C.S. Torres^{1,2}
¹Catalan Institute of Nanotechnology and (ICN-CIN2) Campus Bellaterra, Spain, ²Institute for Research and Advanced Studies, Spain
- P-16 **Dissociation channel of $c\text{-C}_4\text{F}_8$ to CF_2 radical in reactive plasma**
T. Hayashi¹, K. Ishikawa¹, M. Sekine¹, M. Hori¹, A. Kono¹, and K. Suu²
¹Nagoya University, Japan, ²ULVAC Inc., Japan
- P-17 **ANISOTROPIC DRY ETCHING OF ZnO FILMS IN FLUORINE-BASED INDUCTIVELY COUPLED PLASMAS**
J.C. Park¹, H.W. Kim¹, H.J. Jeong², J.H. Koo², G.W. Lee², B.W. Lee², and H. Cho¹
¹Pusan National University, Korea, ²Korea Maritime University, Korea
- P-18 **Investigation of VHF Capacitively Coupled Plasma with DC Bias for Low-k film Etching Process**
T. Kimura¹, T. Yamaguchi¹, K. Takeda^{1,2}, C. Koshimizu³, M. Sekine^{1,2}, and M. Hori^{1,2}
¹Nagoya University, Japan, ²JST-CREST, Japan, ³Tokyo Electron AT Limited, Japan
- P-19 **The Improvement of Metal Etch Under Cut Margin with normal temperature process**
K.-H. HAN^{1,2}, J.-K. LEE², J.-H. SANG², D.-W. KIM, and D.-H. KIM¹
¹Samsung Institute of Technology (SSIT) University, Korea, ²Samsung Electronics Co. Ltd., Korea

- P-20 ***In Situ* Fourier Transform Infrared Diagnostics of Surface Reaction Layers and Reaction Products in Cl₂ Plasma Etching of Si**
H. Miyata, H. Tsuda, Y. Takao, K. Eriguchi, and K. Ono
Kyoto University, Japan
- P-21 **Improvement of Active Pixel Sensor Open Etch Process**
J.-H. YOO^{1,2}, D.-H. KIM¹, J.-J. PARK², J.-S. HYUN², B.-G. JEON², and S.-I. KIM²
¹Samsung Institute of Technology (SSIT) University, Korea, ²Samsung Electronics Co. Ltd., Korea
- P-22 **Atomic-scale analysis of plasma-surface interactions and feature profile evolution by molecular dynamics approaches**
H. Tsuda, T. Nagaoka, Y. Takao, K. Eriguchi, and K. Ono
Kyoto University, Japan
- P-23 **The Improvement of 90nm Metal Etch Under Cut Margin with normal temperature process**
K.-H. HAN^{1,2}, J.-K. LEE², J.-H. SANG², D.-W. KIM, and D.-H. KIM¹
¹Samsung Institute of Technology (SSIT) University, Korea, ²Samsung Electronics Co. Ltd., Korea
- P-24 **Discharge properties of diamond etched by reactive ion etcher with MgO electrode**
T. Misu, S. Ono, T. Higa, M. Goto, K. Koh, and T. Arai
Kanagawa Institute of Technology, Japan
- P-25 **Investigation of Si₃N₄ liner disappearance caused by high density plasma at shallow trench isolation process**
B.-C. CHOI^{1,2}, T.-J. KIM², E.-G. LEE², J.-S. PARK², R.-K. LEE², B.-S. KIM², and D.-H. KIM¹
¹Samsung Institute of Technology (SSIT) University, Korea, ²Samsung Electronics Co. Ltd., Korea
- P-26 **Effects of Plasma Process Fluctuation on Variation in MOS Device Parameters**
K. Eriguchi, Y. Nakakubo, A. Matsuda, M. Kamei, Y. Takao, and K. Ono
Kyoto University, Japan
- P-27 **Study of high voltage transistor (HVTR) leakage path modeling at shallow trench isolation structure**
D.-M. SEO^{1,2}, J.-K. LEE², J.-H. SANG², and S.-O. Choi²
¹Samsung Institute of Technology (SSIT) University, Korea, ²Samsung Electronics Co. Ltd., Korea
- P-28 **Role of Oxygen atoms in the Growth of Magnetron Sputter-Deposited ZnO Films**
A. Morita, J. Jin, and H. Shirai
Saitama University, Japan

- P-30 **New roll coater using microwave plasma for touch screen manufacturing**
I. Liang¹, H. Ogawa¹, K. Kato², K. Iseki³, and H. Sugai¹
¹Chubu University, Japan, ²Nagoya Industrial Research Institute, Japan, ³Toyobo Co. Ltd, Japan
- P-31 **Comparison of wire properties and reliability(TCT,PCT,HTST) between Au-Ag-Pd and 4N Au Wire bonding**
M.-I. KIM^{1,2}, B.-J. KIM², S.-M. Yang², S.-H. LEE², C.-S. LEE², S.-M. SHIN², and D.-H. KIM¹
¹Samsung Institute of Technology (SSIT) University, Korea, ²Samsung Electronics Co. Ltd., Korea
- P-32 **Evaluation of Plasma Sheath Thickness in Reactive Plasmas by Discrete Ion-Focusing Effect**
E. Stamate, and M. Draghici
Technical University of Denmark, Denmark
- P-33 **Deposition of transparent conductive films by a DC Arc Plasmatron**
O.V. Penkov, V.Yu. Plasksin, S.B. Joa, C.H. Kim, and H.J. Lee
Jeju National University, Korea
- P-34 **Deodorant of Sweat by TiO₂ Coated on Wool Textile Using Atmospheric Plasma Jet Supplied with TTIP Solution**
M. Hayakawa, S. Parajulee, and S. Ikezawa
Chubu University, Japan
- P-35 **Plasma Effect on the Physical Properties of Tin Oxide Thin Film**
M. Medhat, H.M. El-Sayed, M.A. Saady, and M. Saleh
Ain Shams University, Egypt
- P-36 **Development of Scratch Test Methodology and Characterization of Surface Damage of Ti (O, N) Film**
S. Parajulee, M. Hayakawa, and S. Ikezawa
Chubu University, Japan
- P-37 **Atmospheric PECVD deposition of nanostructured titanium oxide thin layers by means of barrier-torch discharge**
S. Kment¹, O. Churpita¹, Z. Hubicka¹, M. Cada¹, J. Olejnicek, P. Kluson², and L. Jastrabik¹
¹Institute of Physics AS CR, Czech Republic, ²Institute of Chemical Process Fundamentals AS CR, Czech Republic
- P-38 **Microstructure of Ni-Based Metallic Glass Coating by Gas Tunnel Type Plasma Spraying**
A. Kobayashi¹, T. Kuroda¹, H. Kimura², and A. Inoue²
¹Osaka University, Japan, ²Tohoku University, Japan

- P-39 **Visible light active Photocatalytic properties of nanocrystalline TiO₂ Synthesized by Reactive Plasma Processing**
M. Vijay¹, V. Selvarajan¹, K.P. Sreekumar², and P.V. Ananthapadmanabhan²
¹Bharathiar University, India, ²Bhabha Atomic Research Centre, India
- P-40 **TiO₂ Coating Fabricated by Atmospheric Pressure Microwave Plasma Spray Using Suspension**
T. Kondo, T. Yasui, and M. Fukumoto
Toyohashi University of Technology, Japan
- P-41 **Optical characterization of TiO₂-based plasma sprayed coatings for photocatalytic applications**
P. Ctibor
Academy of Sciences of the Czech Republic, Czech Republic
- P-42 **Enhancement of Reactive Atmospheric Plasma Sprayed Aluminum Particles**
M. Shahien, M. Yamada, T. Yasui, and M. Fukumoto
Toyohashi University of Technology, Japan
- P-43 **Synthesis of DNA Conjugated Gold Nanoparticles Using Gas-Liquid Interfacial Plasmas**
Q. Chen¹, T. Kaneko^{1,2}, and R. Hatakeyama¹
¹Tohoku University, Japan, ²CREST/JST, Japan
- P-44 **Deposition of Hydrophobic Nano-Film on Polymeric Surface with Radio Frequency Fluorocarbon Plasma Polymerization**
C. Huang, C.-I. Lin, C.-H. Pan, and C.-Y. Tsai
Yuan Ze University, Taiwan
- P-45 **Study of the interaction mechanism of colloidal nanoparticles with laser beam**
A. Pyatenko, and N. Koshizaki
National Institute of Advanced Industrial Science and Technology (AIST), Japan
- P-46 **Non-linear properties of lead-based PMN-PT solid solution nanocomposites**
J.-W. Hyun, Y.-J. Kim, and J.-W. Park
Dankook University, Korea
- P-47 **Fabrication of Gold Nanoparticles in Supercritical CO₂-Assisted Pulsed Laser Ablation**
S. Machmudah, Y. Kuwahara, Wahyudiono, M. Sasaki, and M. Goto
Kumamoto University, Japan

- P-48 **Porosity in solids: computer simulation of blistering at nucleation fluctuation stage**
A. Bondareva, and G. Zmievskaya
M.V. Keldysh institute of applied mathematics of Russian Academy of Sciences, Russia
- P-50 **Charging and Magnetizing Characteristics of Co Nanodots**
K. Makihara, A. Kawanami, M. Ikeda, R. Ashihara, and S. Miyazaki
Hiroshima University, Japan
- P-51 **Effect of different sputtering time on the synthesis of copper nano particles grown on AISI 304 substrate by cylindrical magnetron sputtering system**
M. Ghoranneviss, M. Eshghabadi, and A. Mahmoodi
Science and research branch center I.A.U, Iran
- P-52 **Quasi-Bragg grating with sub-wavelength particles**
K. Ishikawa, N. Ebizuka, K. Takeda, H. Kondo, M. Sekine, and M. Hori
Nagoya University, Japan
- P-53 **Toxicity of CIGS nano-particles**
S. Iwashita, H. Miyata, Y. Yamada, K. Koga, M. Shiratani, M. Hirata, Y. Kiyohara, and A. Tanaka
Kyushu University, Japan
- P-54 **Mass Spectrometric Measurement of Neutral Radicals in SiH₄/H₂ High Density Microwave Plasma**
T. Kuroda, T. Ishijima, and H. Toyoda
Nagoya University, Japan
- P-55 **Microcrystalline Silicon Film Deposition by 915 MHz High-Density Microwave Plasma**
J. Sakai, T. Ishijima, and H. Toyoda
Nagoya University, Japan
- P-56 **Analysis of Plasma Interactions with Soft Materials Using Combinatorial Plasma Process Analyzer**
K. Takenaka^{1,4}, Y. Setsuhara^{1,4}, K. Cho^{1,4}, M. Shiratani^{2,4}, M. Sekine^{3,4}, and M. Hori^{3,4}
¹Osaka University, Japan, ²Kyushu University, Japan, ³Nagoya University, Japan, ⁴Japan Science and Technology Agency, CREST, Japan
- P-57 **Protein patterning with selective adsorption on surface by partial plasma polymerization**
H. Takahashi, T. Ii, A. Irie, and H. Mugaruma
Shibaura Institute of Technology, Japan

- P-58 **Experimental Verification of Etching Effect of Microorganism Due to Oxygen Radicals**
Y. Zhao, A. Tsukasaki, A. Ogino, and M. Nagatsu
Shizuoka University, Japan
- P-59 **Study of bacteria sterilization at low discharge voltage by using microplasma**
Y. Komuro, M. Blajan, and K. Shimizu
Shizuoka University, Japan
- P-60 **Analysis of plant nutrients by laser-induced breakdown spectroscopy**
T. Ohta¹, K. Yamamoto¹, and M. Ito²
¹Wakayama University, Japan, ²Meijo University, Japan
- P-61 **Surface-wave Plasma Induced Grafting Polymerization of Polyethylene Glycol onto Polymer Surface and Immobilization of L-Cysteine**
Z. Shao, S. Noguchi, A. Ogino, and M. Nagatsu
Shizuoka University, Japan
- P-62 **Decomposition of Dimethyl Sulfide(DMS) using Atmospheric Argon Micro-plasma System**
H.-H. Chen, C.-C. Weng, J.-D. Liao, W.-H. Kang, L.-M. Whang, C.-C. Chao, and J.-E. Chang
National Cheng Kung University, Taiwan
- P-63 **Observation of Microwave Plasma Ignition in Water using High-Speed Camera and Calculation of Temperature Distribution around Coaxial Electrode**
Y. Hattori, S. Mukasa, S. Nomura, and H. Toyota
Ehime University, Japan
- P-64 **Control of plasma and cavitation bubble in liquid-phase laser ablation by applying supersonic wave**
A. Fujikawa, N. Takada, and K. Sasaki
Nagoya University, Japan
- P-65 **Surface Activation of Poly (vinylidene fluoride) Membrane by Cyclonic Atmospheric Pressure Plasma Processing**
R.-S. Juang, H.-Y. Cheng, C.-Y. Tsai, Y.-C. Chang, and C. Huang
Yuan Ze University, Taiwan
- P-66 **Hollow plate effects on microwave plasma production at high pressure**
S. Ohta¹, I. Liang¹, K. Kato², K. Nakamura¹, and H. Sugai¹
¹Chubu University, Japan, ²Nagoya Industrial Research Institute, Japan

- P-67 **Hydrothermal Pulsed Discharge Plasma for Conversion of Organic Compounds**
Wahyudiono, M. Mitsugi, H. Watanabe, K. Nagafuchi, T. Kiyon, M. Sasaki, H. Akiyama, and M. Goto
Kumamoto University, Japan
- P-68 **Measurements of electron energy distribution accelerated in the cathode region in CCP by using energy analyzer**
T. Matsubara¹, T. Muranaka¹, T. Hayashi¹, A. Kono¹, N. Mizutani², and K. Suu²
¹Nagoya University, Japan, ²ULVAC Inc., Japan
- P-69 **Deposition of Zn_{1-x}Mn_xO thin films by Atmospheric Barrier-Torch Discharge and measurement of electron density from Stark broadening of H_β**
J. Olejnicek, O. Churpita, Z. Hubicka, S. Kment, M. Cada, A. Dejneka, and L. Jastrabik
Institute of Physics AS Cr, Czech Republic
- P-70 **Saturation of the Balmer-α line of atomic hydrogen in diode laser absorption spectroscopy**
R. Asakawa¹, M. Goto², and K. Sasaki¹
¹Nagoya University, Japan, ²National Institute for Fusion Science, Japan
- P-71 **Time Resolved Measurement of H_β Emission from Atmospheric-Pressure Pulsed Microwave Plasma**
A. Kamata, H. Yang, T. Ishijima, and H. Toyoda
Nagoya University, Japan
- P-72 **Measurement of Multiphoton Ionization Efficiency Relevant to Laser Thomson scattering diagnostics**
Y. Matsuda, M. Aramaki, and A. Kono
Nagoya University, Japan
- P-73 **Emission spectroscopy of microplasma in Ar/N₂ mixture for surface treatment applications**
M. Blajan, S. Muramatsu, A. Umeda, and K. Shimizu
Shizuoka University, Japan
- P-74 **Measurement of plasma parameters of atmospheric pressure microplasma jet excited by microwave**
T. Shirasaki, M. Aramaki, and A. Kono
Nagoya University, Japan
- P-75 **Surface Loss Probabilities of H, N Radicals in Afterglow Plasma**
C.S. Moon¹, K. Takeda¹, S. Takashima², M. Sekine^{1,5}, Y. Setsuhara^{3,5}, M. Shiratani^{4,5}, and M. Hori^{1,5}
¹Nagoya University, Japan, ²Plasma Center for Industrial Applications, Japan, ³Osaka University, Japan, ⁴Kyushu University, Japan, ⁵Japan Society of Technology Agency, Japan

- P-76 **Measurements of molecular nitrogen densities in sparkplug assisted atmospheric-pressure microwave discharges using rotational Raman scattering**
M. ElSabbagh¹, S. Kado², M. Kaneko³, Y. Ikeda³, and K. Sasaki¹
¹Nagoya University, Japan, ²The University of Tokyo, Japan, ³Imagineering Inc., Japan
- P-77 **A Stable Large-Volume Fluorine Negative-Ion Source for Ultrafine Etching**
M Abid Imtiaz, and T. Mieno
Shizuoka University, Japan
- P-78 **Effects of amplitude modulation of RF discharge volatage on ion saturation current**
H. Miyata, S. Iwasita, Y. Yamada, K. Koga, and M. Shiratani
Kyushu University, Japan
- P-79 **Synthesis dynamics of nanoparticles produced by laser ablation of a solid target immersed in pressurized water**
W. Soliman, N. Takada, and K. Sasaki
Nagoya University, Japan
- P-80 **XPS Analysis of Plasma-Polymer Interactions for Organic-Inorganic Hybrid Materials**
K. Cho^{1,4}, K. Takenaka^{1,4}, Y. Setsuhara^{1,4}, M. Shiratani^{2,4}, M. Sekine^{3,4}, and M. Hori^{3,4}
¹Osaka University, Japan, ²Kyushu University, Japan, ³Nagoya University, Japan, ⁴Japan Science and Technology Agency, CREST, Japan
- P-81 **H_α emission intensity measurements of H₂+Ar+C₇H₈ plasmas in H-assisted plasma CVD reactor**
T. Nomura¹, Y. Korenaga¹, K. Koga^{1,4}, M. Shiratani^{1,4}, Y. Setsuhara^{2,4}, M. Sekine^{3,4}, and M. Hori^{3,4}
¹Kyushu University, Japan, ²Osaka University, Japan, ³Nagoya University, Japan, ⁴JST CREST, Japan
- P-82 **Ar/H₂O plasma treatment of multiwall carbon nanotubes for dispersion Improvement in water**
C. Chen, A. Ogino, B. Liang, and M. Nagatsu
Shizuoka University, Japan
- P-83 **Deposition of n-type a-Si:H using SiH₄+PH₃ multi-hollow discharge plasma CVD**
K. Nakahara, H. Sato, Y. Kawashima, K. Koga, and M. Shiratani
Kyushu University, Japan
- P-84 **Surface temperature rise of a-Si:H films during deposition in silane multi-hollow discharges**
Y. Kawashima, K. Nakahara, H. Sato, W.M. Nakamura, K. Koga, and M. Shiratani
Kyushu University, Japan

P-85 **Numerical Analysis on Heat Convection in the Synthesis of Single Walled Carbon Nanotubes by Arc Vaporization**

G.-D. Tan, and T. Mieno

Shizuoka University, Japan

P-86 **Effect of Post-Baking on Copper Adhesion to Polyimide Films Treated by High Density Microwave Plasma**

K. Usami¹, T. Ishijima¹, H. Toyoda¹, K. Iseki², H. Sugai³

¹Nagoya University, Japan, ²Toyobo Co. Ltd., Japan, ³Chubu University, Japan

Banquet (19:00-20:30)

Friday, March 12, 2010

Special session on Frontier science of interactions between plasmas and nano-interfaces (9:00-11:50)

- 9:00 S-01 **Frontier science of interactions between plasmas and nano-interfaces**
M. Shiratani, and K. Koga
Kyushu University, Japan
- 9:30 S-02 **Nano-interface plasmas generated in supercritical fluids and their application to nanomaterials processing**
K. Terashima, S. Stauss, H. Miyazoe, T. Shizuno, and K. Saito
The University of Tokyo, Japan
- 10:00 S-03 **Plasmas Involving Liquid Media, and Their Applications**
T. Shirafuji, Y. Noguchi, J. Hieda, N. Saito, and O. Takai
Nagoya University, Japan

Coffee Break (10:30-10:50)

- 10:50 S-04 **Physical control of plasma and cavitation bubble in liquid-phase laser ablation**
K. Sasaki, and N. Takada
Nagoya University, Japan
- 11:20 S-05 **Atmospheric Glow Discharges with Liquid Electrode – Toward Understanding of Plasma-Liquid Interface –**
F. Tochikubo, N. Shirai, and S. Uchida
Tokyo Metropolitan University, Japan

Lunch (11:50-13:00)

Invited Talks 3 (13:00-14:10)

- 13:00 I-08 **Modelling of chlorine inductive discharges**
P. Chabert, and E. Despiau-Pujo
Ecole Polytechnique, France
- 13:35 I-09 **Plasma functionalized carbon nanomaterials for nanocomposite bio-scaffolds and cell viability effects**
O.J. Yoon¹, H.J. Lee², S.S. Kim², and N.-E. Lee¹
¹Sungkyunkwan University, Korea, ²Chung Ang University, Korea

Contributed Talks 2 (14:10-15:10)

- 14:10 O-05 **Population inversion in a magnetized thermal plasma investigated by active and passive spectroscopy**
W.E.N. van Harskamp¹, O. Gabriel², D.C. Schram¹, M.C.M. van de Sanden¹, and R. Engeln¹
¹Eindhoven University of Technology, The Netherlands, ²Helmholtz-Zentrum für Materialien und Energie GmbH, Germany
- 14:30 O-06 **Ultrafast heating in air at atmospheric pressure for nanotechnology applications**
D.Z. Pai, G.D. Stancu, F. Kaddouri, D.A. Lacoste, and C.O. Laux
Ecole Centrale Paris, France
- 14:50 O-07 **Anisotropic film construction using plasma nanotechnology (atomic polymerization)**
L. Hoferek¹, R. Trivedi¹, J. Mistrik^{1,2}, and V. Cech¹
¹Brno University of Technology, Czech Republic, ²University of Pardubice, Czech Republic

Coffee Break (15:10-15:30)

Invited Talks 4 (15:30-17:50)

- 15:30 I-10 **Tailoring nanostructures with low-temperature plasmas**
U. Cvelbar
Jozef Stefan Institute, Slovenia
- 16:05 I-11 **Focused Inert Ion Beam systems for 3D rock tomography on the nano-scale**
R. Boswell, and T. Senden
RSPE, ANU, Australia
- 16:40 I-12 **ZnO nano-materials: Synthesis, Characteristic, and Application**
S.-H. Nam, M.-H. Kim, S.-D. Lee, B. Hong, Y.-J. Kim, and J.-H. Boo
Sungkyunkwan University, Korea
- 17:15 I-13 **With the aim of establishing low-cost fabrication technology for high-performance nitride-based light emitters**
H. Amano, M. Iwaya, S. Kamiyama, and I. Akasaki
Meijo University, Japan
- 17:50 Closing Remarks